2SD2524

Silicon NPN triple diffusion mesa type

For horizontal deflection output

Features

- Incorporating a built-in damper diode
- High breakdown voltage, and high reliability through the use of a glass passivation layer
- High-speed switching
- Wide area of safe operation (ASO)
- Full-pack package with outstanding insulation, which can be installed to the heat sink with one screw

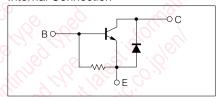
Absolute Maximum Ratings $(T_c=25^{\circ}C)$

Parameter	Symbol	Ratings	Unit	
Collector to base voltage	V _{CBO}	1700	V	
Collector to emitter voltage	V _{CES}	1700	V	
Emitter to base voltage	V_{EBO}	5	V	
Collector current	I_{C}	8	A	
Peak collector current	I _{CP} *	20	Α	
Peak base current	I_{BP}	5	A	
Reverse peak base current	I_{BP}	-4.5	A	
Collector power T _C =25°C	D	100	7,77	
dissipation Ta=25°C	P_{C}	3	SO W NO	
Junction temperature	T _j	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C O	

Storage temperature T_{stg}
*Non-repetitive peak

Unit: mm 15.5±0.5 03.2±0.1 15.5±0.5 03.2±0.1 15.5±0.5 03.2±0.1 15.5±0.3 15.5±0.3 1.Base 2:Collector 3:Emitter TOP–3E Full Pack Package

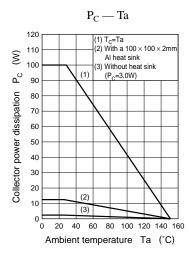
Internal Connection

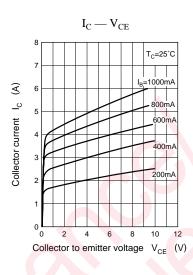


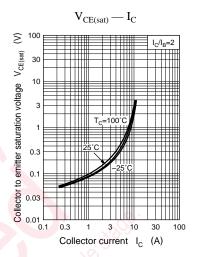
Electrical Characteristics (T_C=25°C)

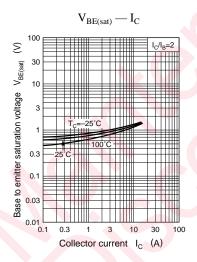
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 1000V, I_E = 0$			50	μΑ
		$V_{CB} = 1700V, I_E = 0$			1	mA
Emitter to base voltage	V _{EBO}	$I_E = 500 \text{mA}, I_C = 0$	5			V
Forward current transfer ratio	h _{FE}	$V_{CE} = 5V, I_C = 6A$	4		10	
Collector to emitter saturation voltage	V _{CE(sat)}	$I_C = 6A, I_B = 2A$			3	V
Base to emitter saturation voltage	V _{BE(sat)}	$I_C = 6A, I_B = 2A$			1.5	V
Transition frequency	f_{T}	$V_{CE} = 10V, I_{C} = 0.1A, f = 0.5MHz$		3		MHz
Storage time	t _{stg}	I (A I 2A I 5II			12	μs
Fall time	$t_{\rm f}$	$I_{\rm C} = 6A$, $I_{\rm Bend} = 2A$, $L_{\rm leak} = 5\mu H$			0.8	μs
Diode forward voltage	V _F	$I_C = 8A, I_B = 0$			-2	V

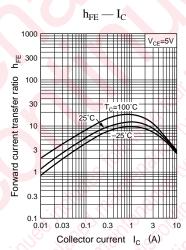
Power Transistors 2SD2524

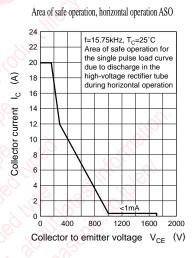


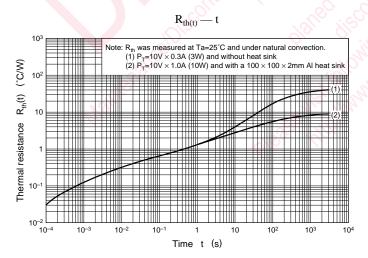












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